TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

## SSM6N05FU

#### **High Speed Switching Applications**

- Small package
- Low on resistance :  $R_{on}$  = 0.8  $\Omega$  (max) (@VGS = 4 V) :  $R_{on}$  = 1.2  $\Omega$  (max) (@VGS = 2.5 V)
- Low gate threshold voltage

# Absolute Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristics		Symbol	Rating	(Unit )	
Drain-Source voltage		$V_{DS}$	20	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	
Gate-Source voltage		V <sub>GSS</sub>	±1,2	V	
Drain current	DC	ΙD	400	mA	
	Pulse	I <sub>DP</sub>	800		
Drain power dissipation (Ta = 25°C)		P <sub>D</sub> (Note 1)	300	mW	
Channel temperature		T <sub>ch</sub>	150	//°C	
Storage temperature range		T <sub>stg</sub>	-55~150	ŝ	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the

Weight: 6.8 mg (typ.)

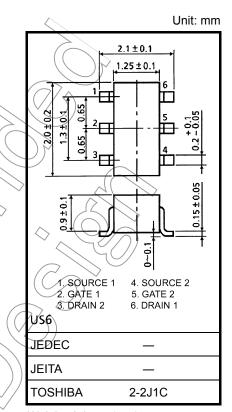
reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Total rating, mounted on FR4 board (25.4 mm  $\times$  25.4 mm  $\times$  1.6 t, Cu Pad: 0.32 mm $^2$   $\times$  6)

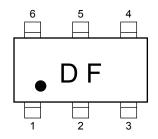
### **Handling Precaution**

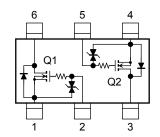
When handling individual devices (which are not yet mounting on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.



#### Marking

#### **Equivalent Circuit (top view)**



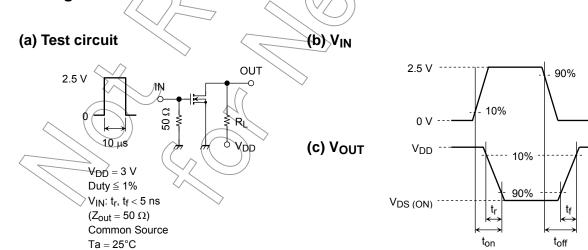


## Electrical Characteristics (Ta = 25°C) (Q1, Q2 common)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I <sub>GSS</sub>	$V_{GS} = \pm 12 \text{ V}, V_{DS} = 0$		4	<b>₽</b> 1	μΑ
Drain-Source breakdown voltage		V (BR) DSS	I <sub>D</sub> = 1 mA, V <sub>GS</sub> =0	20		> —	V
Drain cut-off current		I <sub>DSS</sub>	V <sub>DS</sub> = 20 V, V <sub>GS</sub> = 0	7		) 1	μА
Gate threshold voltage		V <sub>th</sub>	$V_{DS} = 3 V$ , $I_{D} = 0.1 \text{ mA}$	0.6	90)	1.1	V
Forward transfer admit	tance	Yfs	V <sub>DS</sub> = 3 V, I <sub>D</sub> = 200 mA (Note2)	350	> _	_	mS
Drain-Source ON resistance		R <sub>DS</sub> (ON)	$I_D = 200 \text{ mA}, V_{GS} = 4 \text{ V}$ (Note2)	/	0.6	0.8	Ω
			I <sub>D</sub> = 200 mA, V <sub>GS</sub> = 2.5 V (Note2)	\	0.85	1.2	
Input capacitance		C <sub>iss</sub>		/ _	22	_	pF
Reverse transfer capacitance		C <sub>rss</sub>	$V_{DS} = 3 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	9	_	pF
Output capacitance		Coss	·	_	21	_	pF
Switching time	Turn-on time	ton	V <sub>DD</sub> = 3 V, I <sub>D</sub> = 100 mA,	—	60	_	ns
	Turn-off time	toff	V <sub>GS</sub> = 0~2.5 V		70	_	

Note2: Pulse test

## Switching Time Test Circuit

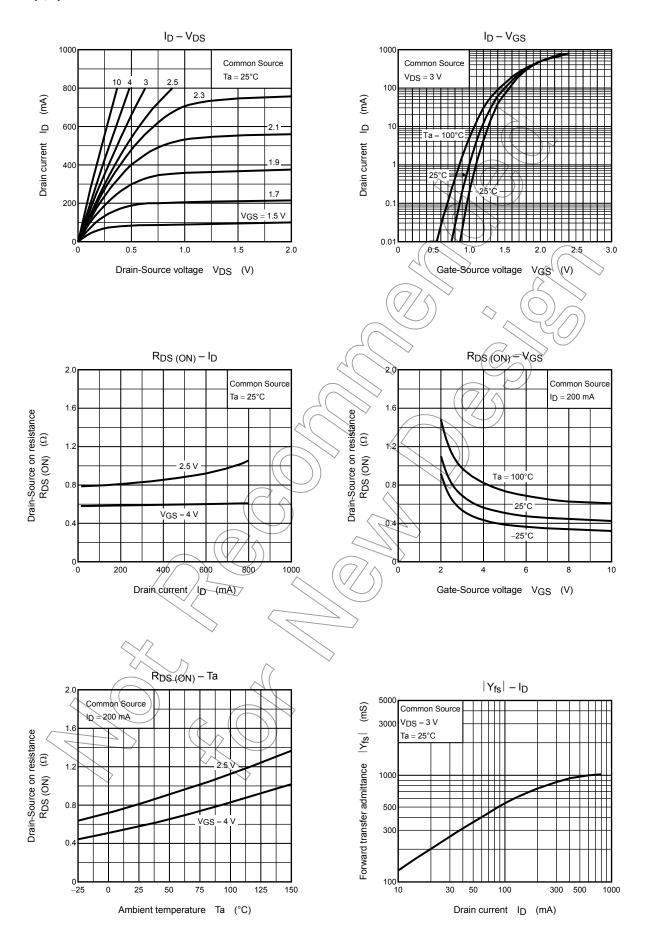


#### **Precaution**

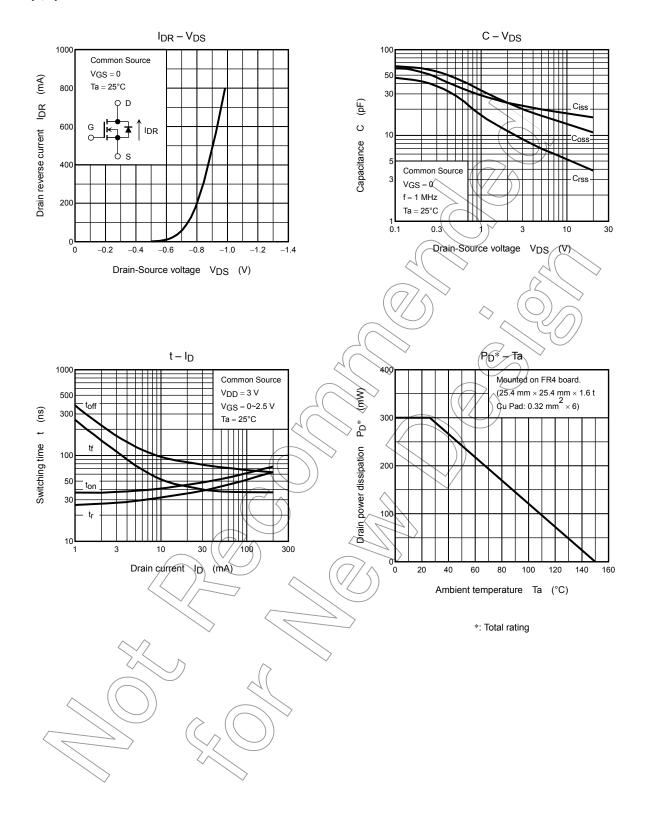
 $V_{th}$  can be expressed as voltage between gate and source when low operating current value is  $I_D$  = 100  $\mu A$  for this product. For normal switching operation,  $V_{GS}$  (on) requires higher voltage than  $V_{th}$  and  $V_{GS}$  (off) requires lower voltage than  $V_{th}$ . (Relationship can be established as follows:  $V_{GS}$  (off) <  $V_{th}$  <  $V_{GS}$  (on))

Please take this into consideration for using the device.

(Q1, Q2 common)



(Q1, Q2 common)



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